

NPN Silicon Transistor

С

в

С

F

[Ta=25℃]

 $(Ta=25^{\circ}C)$

PIN Connection

Applications

- Power amplifier application
- High current switching application

Features

- Power Transistor General Purpose application
 - Low saturation voltage
 - : V_{CE(sat)}=0.4V Typ.
- High Voltage : V_{CEO}=65V Min.

Ordering Information

e : V_{CEO}=65V Min. **TO-252**

в

Туре NO.	Marking	Package Code
STC503D	STC503	TO-252

Absolute Maximum Ratings

Characteristic	Symbol	Rating	Unit	
Collector-Base voltage	V _{CBO}	80	V	
Collector-Emitter voltage	V _{CEO}	65	V	
Emitter-base voltage	V _{EBO}	5	V	
Collector current	Ι _C	3	A(DC)	
collector current	I _{CP} *	6	A(Pulse)	
Collector Power dissipation	$P_{C}(Ta = 25^{\circ}C)$	1	W	
collector Power dissipation	$P_{C}(T_{C}=25^{\circ}C)$	10	W	
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55~150	°C	

*: Single pulse, tp= $300 \ \mu s$

Characteristic		Symbol	Тур.	Max	Unit
Thermal resistance	Junction-ambient	R _{th(J-a)}	-	125.0	°C/W
Thermal resistance	Junction-case	R _{th(J-c)}	-	12.5	°C/W

Electrical Characteristics

					(1a-25 C)		
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit	
Collector-Emitter breakdown voltage	BV _{CEO}	$I_{C}=1mA$, $I_{B}=0$	65	-	-	V	
Collector cut-off current	I _{CBO}	$V_{CB} = 65V, I_{E} = 0$	-	-	50	μA	
Emitter cut-off current	I _{EBO}	$V_{EB}=5V$, $I_{C}=0$	-	-	50	μA	
DC current gain	h _{FE} *	$V_{CE} = 5V, I_{C} = 0.5A$	300	-	500	-	
Base-Emitter on voltage	V _{BE(ON)}	$V_{CE} = 5V, I_{C} = 0.5A$	-	0.7	1	V	
Collector-Emitter saturation voltage	V _{CE(sat)}	$I_{C}=2A, I_{B}=0.2A$	-	0.4	1	V	
Transition frequency	f _T	V_{CB} =5V, I_{C} =50mA	-	250	-	MHz	
Collector output capacitance	C _{ob}	V_{CB} =10V, I_E =0, f=1MHz	-	15	-	рF	

* hFE rank : 300~500 Only

Electrical Characteristic Curves

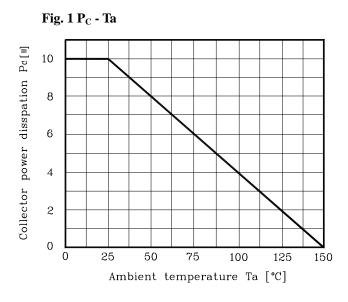
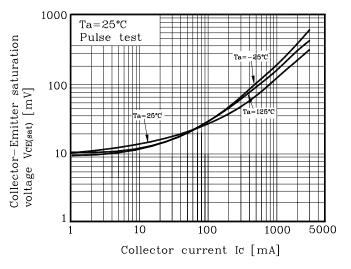
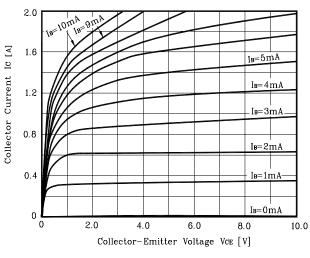
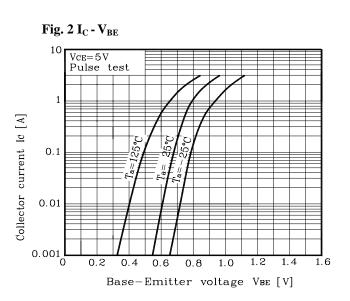


Fig. 3 $V_{CE(sat)}$. I_C

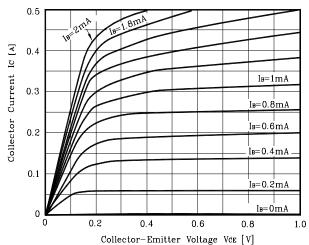


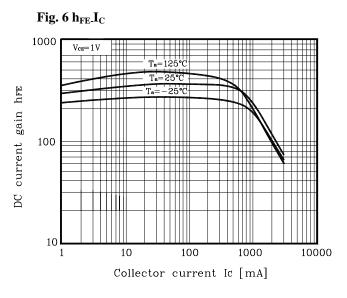












Electrical Characteristic Curves

0.01

0.001

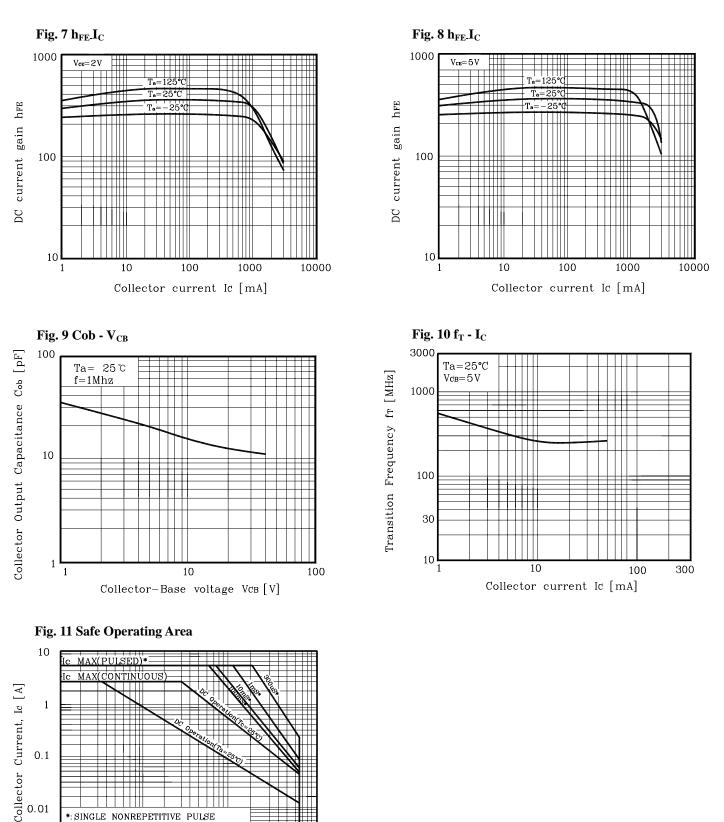
0.1

*: SINGLE NONREPETITIVE PULSE $(Tc=25^{\circ}C)$ CURVES MUST BE DERATED LINERLY WITH INCREASE IN TEMPERATURE

1

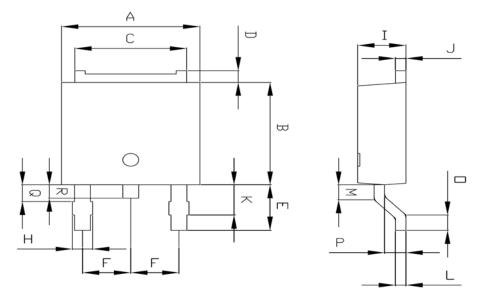
10

Collector-Emitter Voltage Vcm [V]



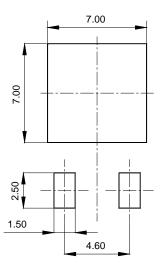
100

Outline Dimension



	MILLIMETERS			NOTE
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	NUTE
Α	6.40	6.60	6.80	
В	5.90	6.10	6.30	
C	5.04	5.34	5.64	
D	0.50	0.70	0.90	
E	2.50	2.70	2.90	
F	2.10	2.30	2.50	
Н				
- I	2.20	2.30	2.40	
J	0.40	0.50	0.60	
K	1.60	1.80	2.00	
L	0.40	0.50	0.60	
М	0.81	0.91	1.01	
0	0.80	0.90	1.00	
Ρ	0.90	1.00	1.10	
Q		0.95 MAX		
R	0.60	0.80	1.00	

*Recommend PCB solder land [Unit: mm]



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